

DDH INFRARED EMITTING DIODE

PRELIMINARY

■ GENERAL DESCRIPTION

The NJL1127L is DDH (Dissubstrate Double Heterstructure) infrared LED of high speed and high efficiency. Output light power is 2.5 times of usual LED.

The NJL1127L is suitable for the light source of codeless optical communications, LAN system, and optical fiber communication.

The NJL1127L is 2-pin package of 5mmφ visible molding compound. The NJL1127L corresponds to EIAJ CP-1205, BAND V (6MHz~30MHz).

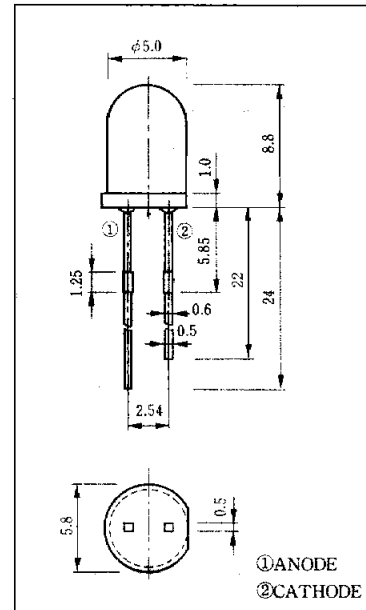
■ FEATURES

- High speed  $f_c=30\text{MHz}$
- High output power  $\phi_e=15\text{mW}$

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Forward Current (Continuous)	$I_F$	60	mA
Pulse Forward Current	$I_{FP}$	800(Note1)	mA
Reverse Voltage (Continuous)	$V_R$	6	V
Power Dissipation	$P_D$	120	mW
Operating Temperature	$T_{opr}$	-20~+90	°C
Storage Temperature	$T_{sig}$	-30~+100	°C
Soldering Temperature	$T_{sol}$	260(Note2)	°C

■ OUTLINE (typ.) Unit: mm



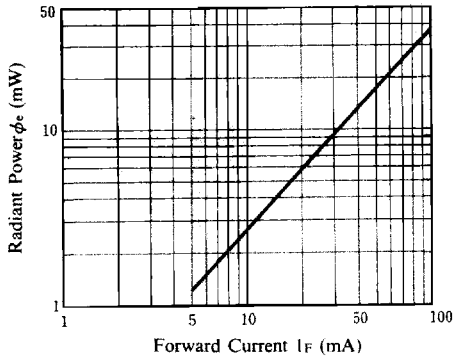
■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Radiant Power	$\phi_e$	$I_F=50\text{mA}$	--	15	--	mW
Peak Wave Length	$\lambda_p$	$I_F=50\text{mA}$	--	850	--	nm
Spectral Line Halfwidth	$\Delta\lambda$	$I_F=50\text{mA}$	--	40	--	nm
Forward Voltage	$V_F$	$I_F=50\text{mA}$	--	1.6	--	V
Reverse Current	$I_R$	$V_R=6\text{V}$	--	--	10	$\mu\text{A}$
Capacitance	$C_i$	$V_R=0\text{V}, f=1\text{MHz}$	45	70	90	pF
Rise Time	$t_r$	$I_F=50\text{mA}$	--	10	--	ns
Fall Time	$t_f$	$I_F=50\text{mA}$	--	10	--	ns
Cut-off Frequency	$f_c$	$I_F=50\text{mA}$	--	30	--	MHz

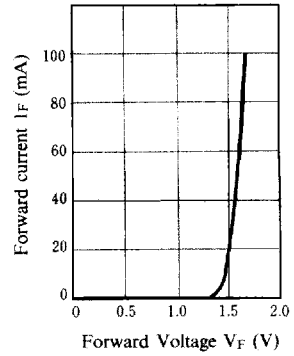
## ■ TYPICAL CHARACTERISTICS

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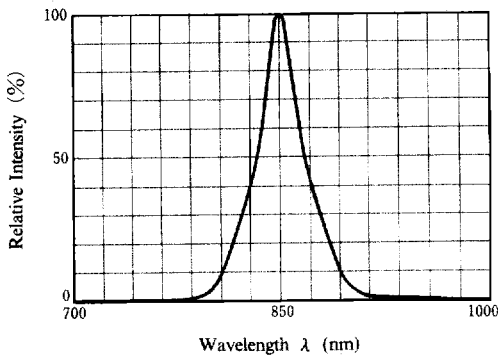
**Radiant Power vs. Forward Current** ( $T_a=25\text{ }^\circ\text{C}$ )



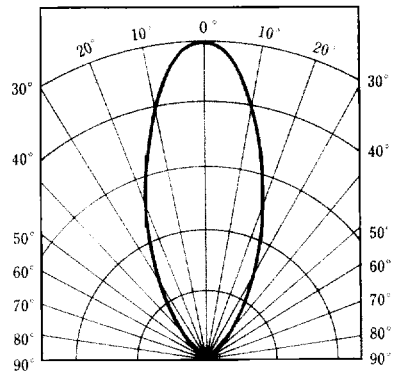
**Forward Current vs. Forward Voltage** ( $T_a=25\text{ }^\circ\text{C}$ )



**Relative intensity vs. Wavelength** ( $T_a=25\text{ }^\circ\text{C}$ )



**Typical Radiation Pattern** ( $T_a=25\text{ }^\circ\text{C}$ )



**Frequency Characteristics** ( $T_a=25\text{ }^\circ\text{C}$ )

